

HMHA281, HMHA2801 Series

4-Pin Half-Pitch Mini-Flat Phototransistor Optocouplers

Description

The HMHA281 and HMHA2801 series devices consist of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 1.27 mm.

Features

- Compact 4-Pin Package
 - ◆ 2.4 mm Maximum Standoff Height
 - ◆ Half-Pitch Leads for Optimum Board Space Savings
- Current Transfer Ratio:
 - ◆ HMHA281: 50% to 600%
 - ◆ HMHA2801: 80% to 600%
 - ◆ HMHA2801A: 80% to 160%
 - ◆ HMHA2801B: 50% to 150%
 - ◆ HMHA2801C: 50% to 100%
- Safety and Regulatory Approvals:
 - ◆ UL1577, 3.750 VAC_{RMS} for 1 Minute
 - ◆ DIN-EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage
- These Devices are Pb-Free and are RoHS Compliant

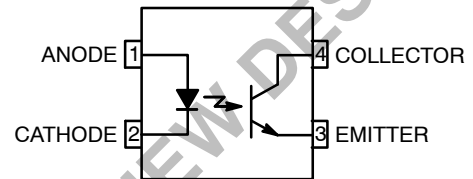
Applications

- Digital Logic Inputs
- Microprocessor Inputs
- Power Supply Monitor
- Twisted Pair Line Receiver
- Telephone Line Receiver

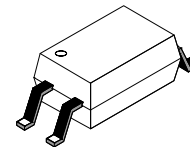


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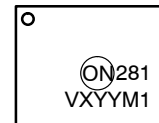


Phototransistor Optocoupler



MPF4
CASE 100AL

MARKING DIAGRAM



- ON = onsemi Logo
281 = Device Number
V = DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
X = One-Digit Year Code, e.g., "5"
YY = Digit Work Week, Ranging from "01" to "53"
M1 = Assembly Package Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

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Table 1. SAFETY AND INSULATION RATINGS (As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for “safe electrical insulation” only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Parameter		Characteristics
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage	< 150 V _{RMS}	I–IV
	< 300 V _{RMS}	I–III
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V _{PR}	Input-to-Output Test Voltage, Method A, V _{IORM} × 1.6 = V _{PR} , Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC	904	V _{peak}
	Input-to-Output Test Voltage, Method B, V _{IORM} × 1.875 = V _{PR} , 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC	1060	V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	565	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	4000	V _{peak}
	External Creepage	≥5	mm
	External Clearance	≥5	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.4	mm
T _S	Case Temperature (Note 1)	150	°C
I _{S, INPUT}	Input Current (Note 1)	200	mA
P _{S, OUTPUT}	Output Power (Note 1)	300	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V (Note 1)	>10 ⁹	Ω

1. Safety limit values – maximum values allowed in the event of a failure.

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ABSOLUTE MAXIMUM RATINGS (T_C = 25°C, Unless otherwise specified)

Symbol	Parameter	Value	Unit
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TOTAL PACKAGE

T _{STG}	Storage Temperature	-55 to +125	°C
T _{OPR}	Operating Temperature	-55 to +100	°C
T _J	Junction Temperature	-40 to +125	°C
P _D	Total Device Power Dissipation @ T _A = 25°C	210	mW
	Derate Above 25°C	2.1	mW/°C

EMITTER

I _{F (avg)}	Continuous Forward Current	50	mA
I _{F (pk)}	Peak Forward Current (1 μs pulse, 300 pps)	1	A
V _R	Reverse Input Voltage	6	V
P _D	LED Power Dissipation @ T _A = 25°C	60	mW
	Derate Above 25°C	0.6	mW/°C

DETECTOR

I _C	Continuous Collector Current	50	mA
V _{CEO}	Collector-Emitter Voltage	80	V
V _{ECO}	Emitter-Collector Voltage	7	V
P _D	Detector Power Dissipation @ T _A = 25°C	150	mW
	Derate Above 25°C	1.5	mW/°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Symbol	Parameter	Test Conditions	Device	Min	Typ	Max	Unit
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INDIVIDUAL COMPONENT CHARACTERISTICS

Emitter

V _F	Forward Voltage	I _F = 10 mA	All	1.0	–	1.3	V
I _R	Reverse Current	V _R = 5 V	All	–	–	5	μA

Detector

BV _{CEO}	Breakdown Voltage Collector to Emitter	I _C = 0.5 mA, I _F = 0	All	80	–	–	V
BV _{ECO}	Emitter to Collector	I _E = 100 μA, I _F = 0	All	7	–	–	
I _{CEO}	Collector Dark Current	V _{CE} = 80 V, I _F = 0	All	–	–	100	nA
C _{CE}	Capacitance	V _{CE} = 0 V, f = 1 MHz	All	–	10	–	pF

TRANSFER CHARACTERISTICS

CTR	DC Current Transfer Ratio	I _F = 5 mA, V _{CE} = 5 V	HMHA281	50	–	600	%
			HMHA2801	80	–	600	
			HMHA2801A	80	–	160	
			HMHA2801B	50	–	150	
		I _F = 1 mA, V _{CE} = 5 V	HMHA2801C	50	–	100	
V _{CE (SAT)}	Saturation Voltage	I _F = 8 mA, I _C = 2.4 mA	HMHA281	–	–	0.4	V
		I _F = 10 mA, I _C = 2 mA	HMHA2801, HMHA2801A, HMHA2801B, HMHA2801C	–	–	0.3	
t _r	Rise Time (Non-Saturated)	I _C = 2 mA, V _{CE} = 5 V, R _L = 100 Ω	All	–	3	–	μs
t _f	Fall Time (Non-Saturated)	I _C = 2 mA, V _{CE} = 5 V, R _L = 100 Ω	All	–	3	–	

ISOLATION CHARACTERISTICS

V _{ISO}	Steady State Isolation Voltage	1 Minute	All	3750	–	–	VAC _{RMS}
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

HMHA281, HMHA2801 Series

TYPICAL PERFORMANCE CHARACTERISTICS

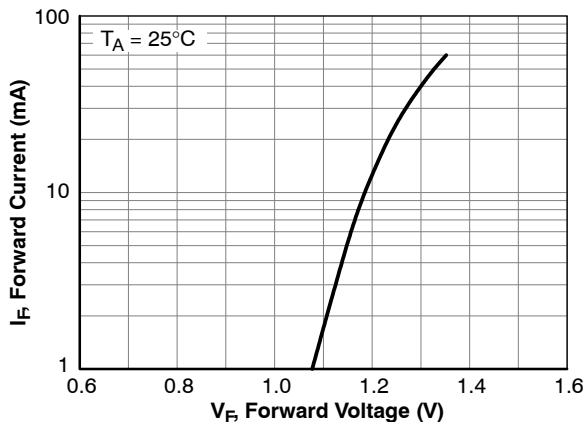


Figure 1. Forward Current vs. Forward Voltage

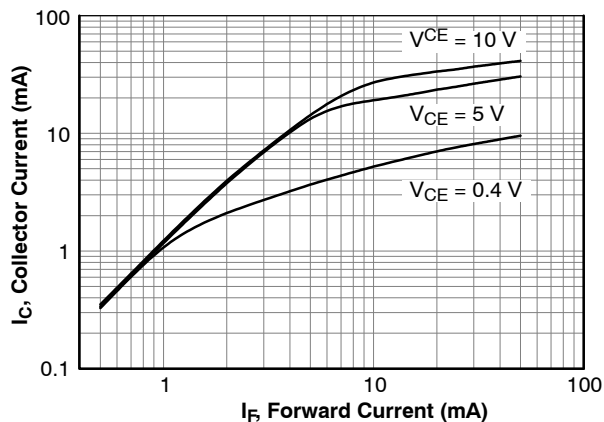


Figure 2. Collector Current vs. Forward Current

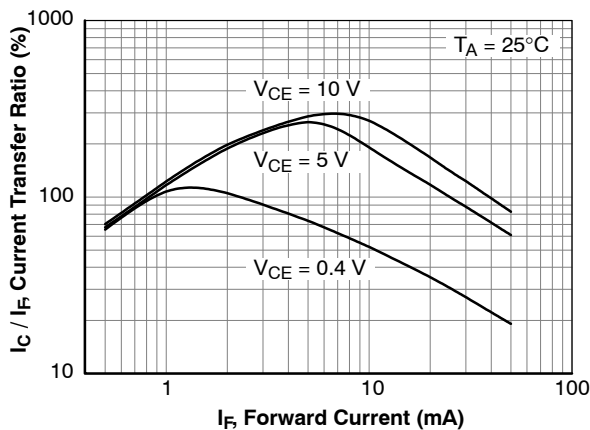


Figure 3. Current Transfer Ratio vs. Forward Current

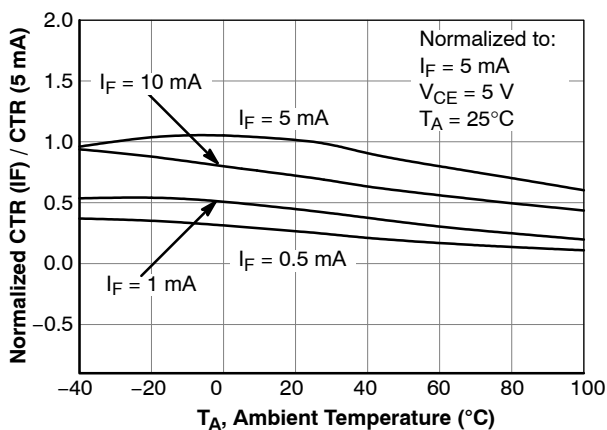


Figure 4. Normalized CTR vs. Temperature

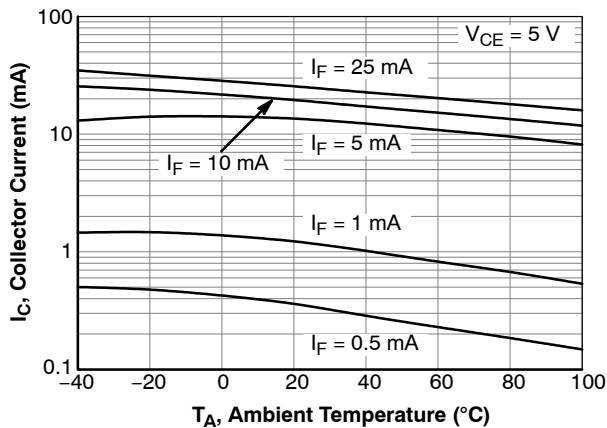


Figure 5. Collector Current vs. Temperature

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TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

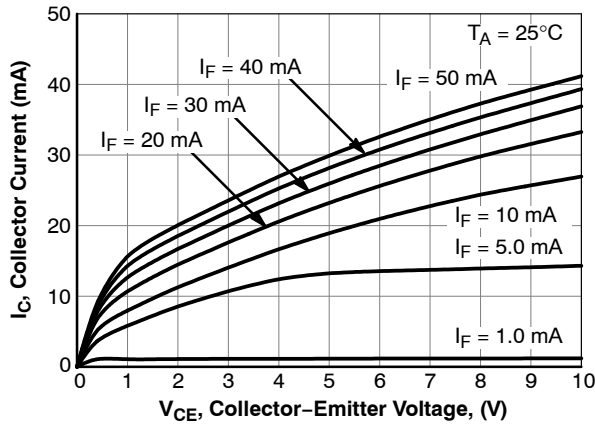


Figure 6. Collector Current vs. Collector-Emitter Voltage

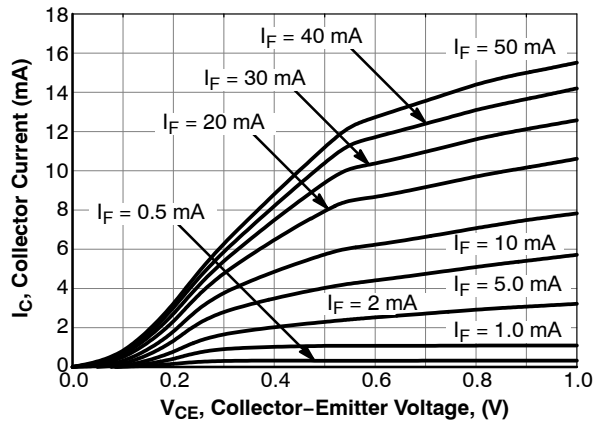


Figure 7. Collector Current vs. Collector-Emitter Voltage

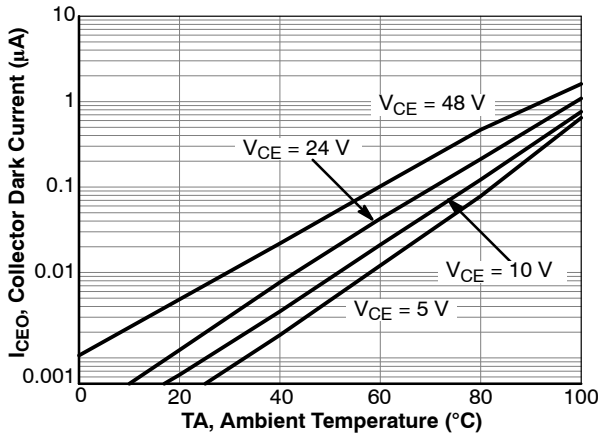


Figure 8. Collector Dark Current vs. Temperature

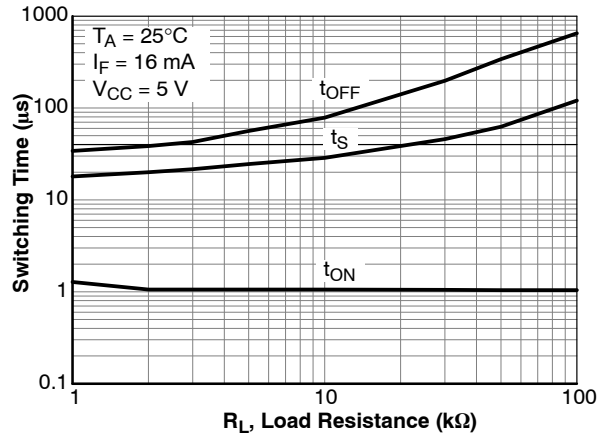


Figure 9. Switching Time vs. Load Resistance

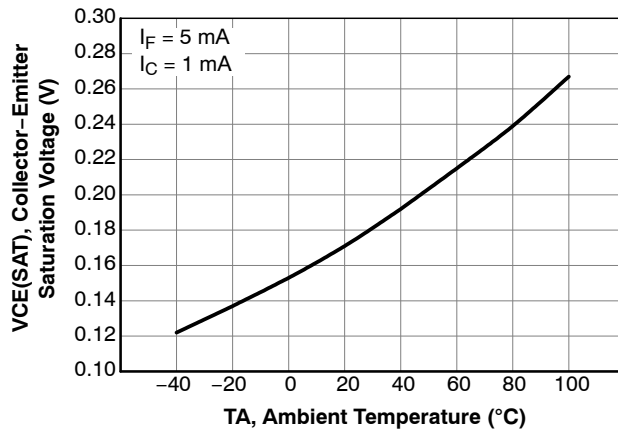


Figure 10. Collector-Emitter Saturation Voltage vs Temperature

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REFLOW PROFILE

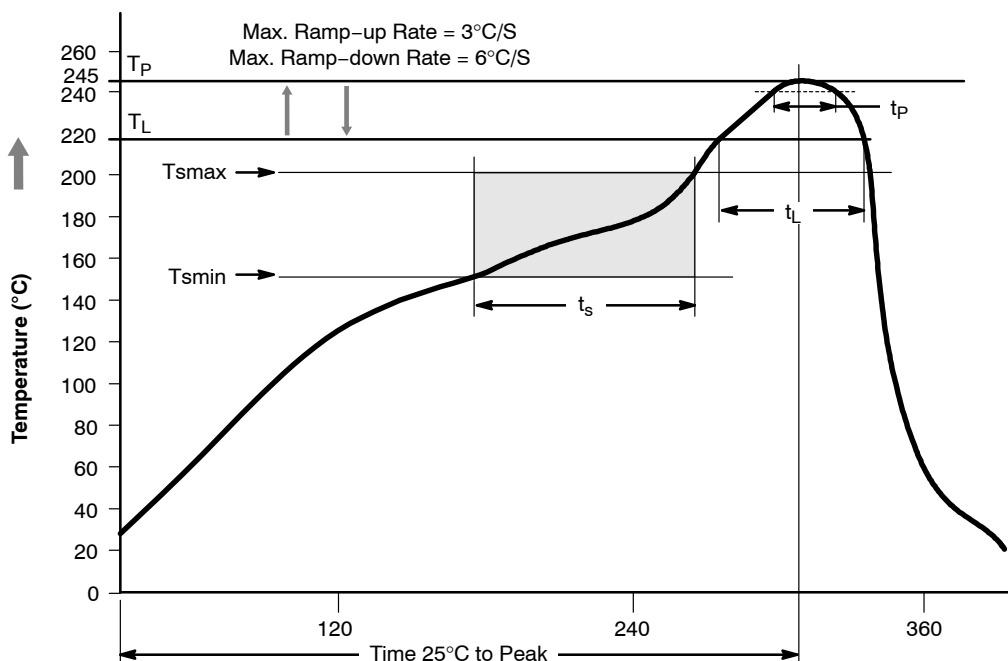


Figure 11. Reflow Profile

*For applications requiring 260C peak reflow performance, please order FODM217 series.

Profile Feature	Pb-Free Assembly Profile
Temperature Minimum (T _{smin})	150°C
Temperature Maximum (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60 – 120 seconds
Ramp-up Rate (t _L to t _P)	3°C / second maximum
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	245°C +0°C / -5°C
Time (t _P) within 5°C of 245°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C / second maximum
Time 25°C to Peak Temperature	8 minutes maximum

ORDERING INFORMATION

Part Number	Package	Shipping [†]
HMHA2801	Half Pitch Mini-Flat 4-Pin	150 Units / Tube
HMHA2801R2	Half Pitch Mini-Flat 4-Pin	2500 / Tape & Reel
HMHA2801V	Half Pitch Mini-Flat 4-Pin, DIN EN/IEC60747-5-5 Option	150 Units / Tube
HMHA2801R2V	Half Pitch Mini-Flat 4-Pin, DIN EN/IEC60747-5-5 Option	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

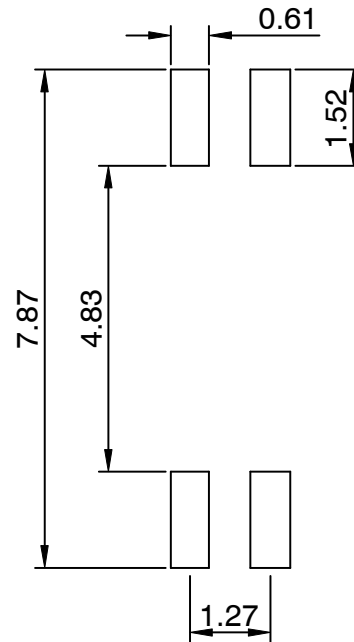
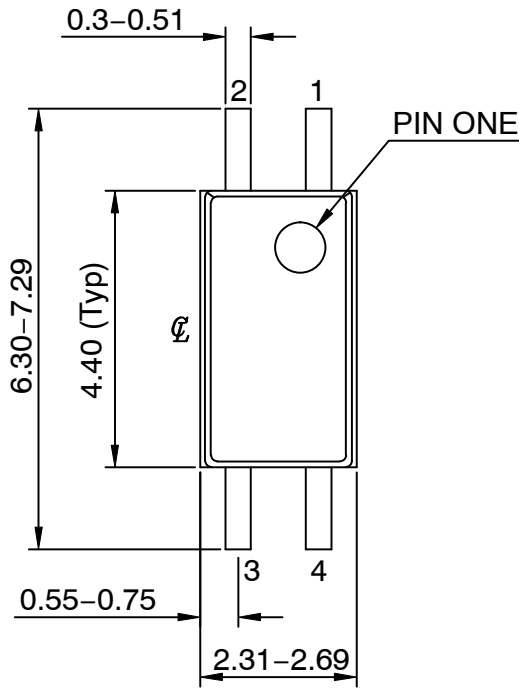
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

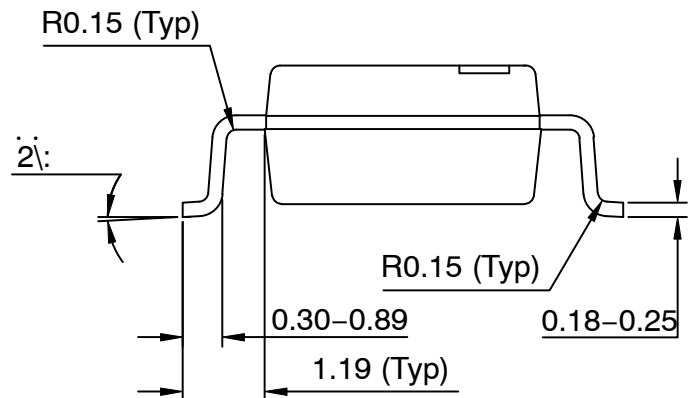
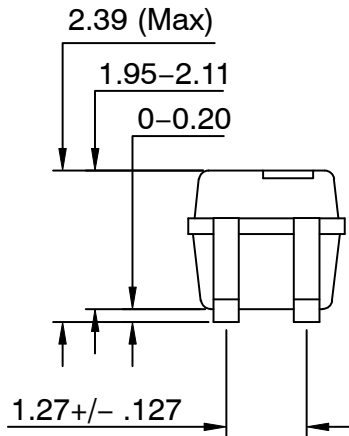


MFP4 2.5X4.4, 1.27P
CASE 100AL
ISSUE O

DATE 31 AUG 2016



LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION

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